

# **DESCRIPTION**

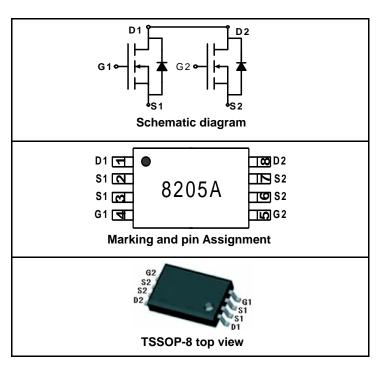
The SSF8205A uses advanced trench technology to provide excellent  $R_{\text{DS(ON)}}$ , low gate charge and operation with gate voltages as low as 0.65V. This device is suitable for use as a Battery protection or in other Switching application.

#### **GENERAL FEATURES**

- $V_{DS} = 20V, I_D = 6A$   $R_{DS(ON)} < 37.5mΩ$  @  $V_{GS} = 2.5V$  $R_{DS(ON)} < 27.5mΩ$  @  $V_{GS} = 4.5V$
- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

## **Application**

- Battery protection
- Load switch
- Power management



#### PACKAGE MARKING AND ORDERING INFORMATION

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
8205A	SSF8205A	TSSOP-8	Ø330mm	12mm	3000 units

#### ABSOLUTE MAXIMUM RATINGS(TA=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	20	V
Gate-Source Voltage	V <sub>G</sub> s	±10	V
Drain Current Continuous @ Current Duland (Note 1)	I <sub>D</sub>	6	А
Drain Current-Continuous@ Current-Pulsed (Note 1)	I <sub>DM</sub>	25	Α
Maximum Power Dissipation	P <sub>D</sub>	1.5	W
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 150	$^{\circ}$

#### THERMAL CHARACTERISTICS

		00	00 001
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	83	℃W

#### **ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)**

Parameter	Symbol	Condition	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	20			V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =18V,V <sub>GS</sub> =0V			1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}=\pm10V, V_{DS}=0V$			±100	nA
ON CHARACTERISTICS (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_D=250\mu A$	0.5	0.65	1.2	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	$V_{GS}$ =4.5 $V$ , $I_{D}$ =4.5 $A$		21	27.5	mΩ
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =3.5A		30	37.5	mΩ



# SSF8205A

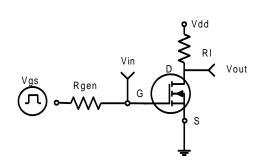
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =4.5A	10		S
DYNAMIC CHARACTERISTICS (Note4)					
Input Capacitance	C <sub>Iss</sub>		600		PF
Output Capacitance	Coss	$V_{DS}=8V,V_{GS}=0V,$ F=1.0MHz	330		PF
Reverse Transfer Capacitance	C <sub>rss</sub>	1 – 1.01/11/12	140		PF
SWITCHING CHARACTERISTICS (Note 4)					
Turn-on Delay Time	t <sub>d(on)</sub>		10	20	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =10V, $I_{D}$ =1A $V_{GS}$ =4.5V, $R_{GEN}$ =6 $\Omega$	11	25	nS
Turn-Off Delay Time	t <sub>d(off)</sub>		35	70	nS
Turn-Off Fall Time	t <sub>f</sub>		30	60	nS
Total Gate Charge	Qg		10	15	nC
Gate-Source Charge	$Q_{gs}$	$V_{DS}=10V,I_{D}=6A,$ $V_{GS}=4.5V$	2.3		nC
Gate-Drain Charge	$Q_gd$	V GS-4.5 V	3		nC
DRAIN-SOURCE DIODE CHARACTERISTICS					•
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =1.7A	0.72	1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>			1.7	Α

# **NOTES:**

- Repetitive Rating: Pulse width limited by maximum junction temperature.
   Surface Mounted on FR4 Board, t ≤ 10 sec.
   Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
   Guaranteed by design, not subject to production testing.



# TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS



**Figure 1:Switching Test Circuit** 

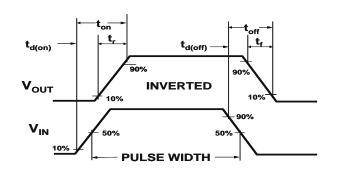
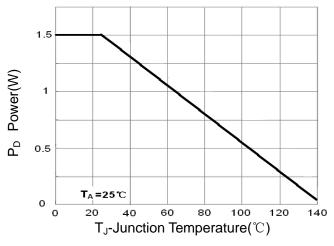
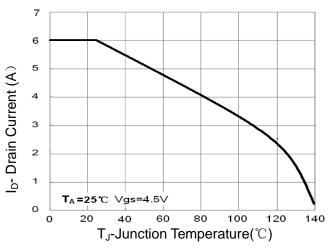


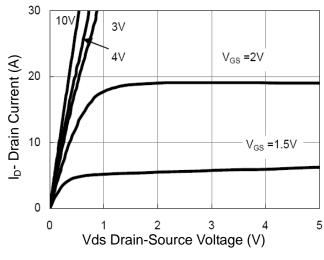
Figure 2:Switching Waveforms



**Figure 3 Power Dissipation** 



**Figure 4 Drain Current** 



**Figure 5 Output CHARACTERISTICS** 

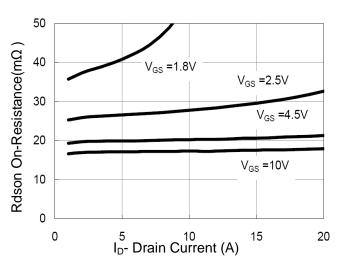
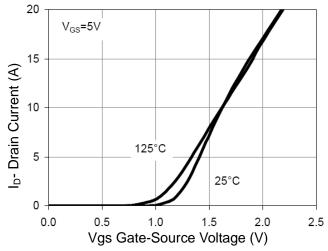


Figure 6 Drain-Source On-Resistance





**Figure 7 Transfer Characteristics** 

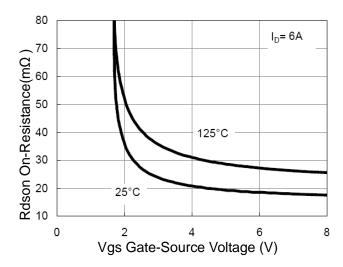


Figure 9 Rdson vs Vgs

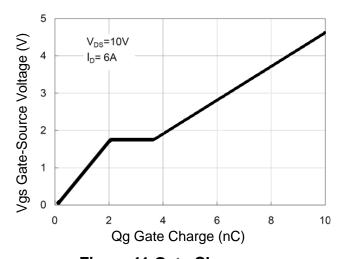


Figure 11 Gate Charge

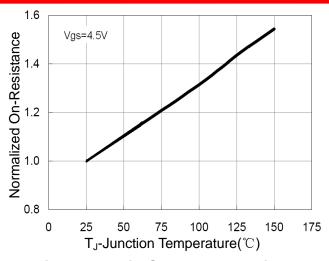


Figure 8 Drain-Source On-Resistance

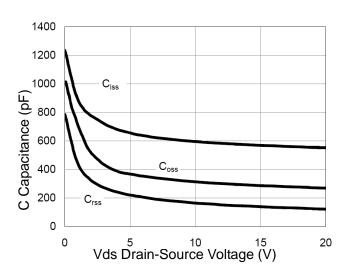


Figure 10 Capacitance vs Vds

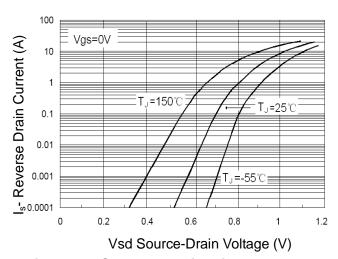


Figure 12 Source- Drain Diode Forward



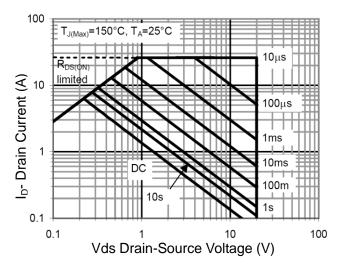
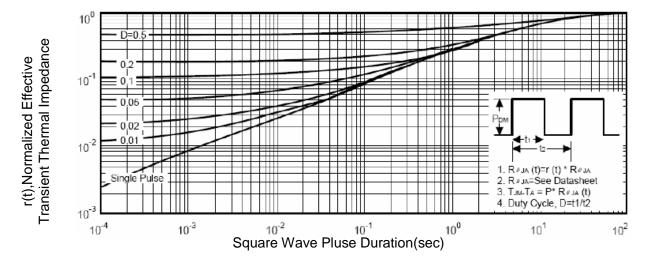


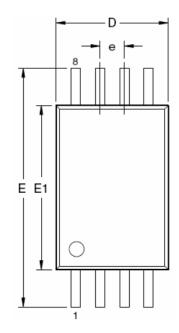
Figure 13 Safe Operation Area

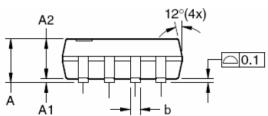


**Figure 14 Normalized Maximum Transient Thermal Impedance** 

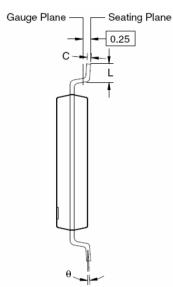


# **TSSOP-8 PACKAGE INFORMATION**

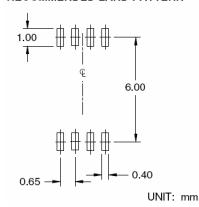




# **Dimensions in Millimeters (UNIT:mm)**



## RECOMMENDED LAND PATTERN



## **Dimensions in millimeters**

Symbols	Min.	Nom.	Max.	
Α	_	_	1.20	
A1	0.05	_	0.15	
A2	0.80	1.00	1.05	
b	0.19	_	0.30	
С	0.09	_	0.20	
D	2.90	3.00	3.10	
E	6.40 BSC			
E1	4.30	4.40	4.50	
е	0.65 BSC			
L	0.45	0.60	0.75	
θ	0°	_	8°	

#### Dimensions in inches

Symbols	Min.	Nom.	Max.		
Α	l		0.047		
A1	0.002	_	0.006		
A2	0.031	0.039	0.041		
b	0.007	_	0.012		
С	0.004		0.008		
D	0.114	0.118	0.122		
Е	0.252 BSC				
E1	0.169	0.173	0.177		
е	0.026 BSC				
L	0.018	0.024	0.030		
θ	0°	_	8°		

#### NOTES:

- 1. All dimensions are in millimeters.
- Dimensions are inclusive of plating
   Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 6 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



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